3.0A ULTRAFAST DIODE

### **Features**

- Diffused Junction
- Low Forward Voltage Drop
- High Surge Current Capability
- High Reliability
- Ideally Suited for Use in High Frequency SMPS, Inverters and As Free Wheeling Diodes

## **Mechanical Data**

Case: DO-201AD, Molded Plastic

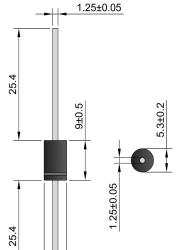
Terminals: Plated Leads Solderable per

MIL-STD-202, Method 208 Polarity: Cathode Band

• Weight: 1.2 grams (approx.)

Mounting Position: AnyMarking: Type Number

Lead Free: For RoHS / Lead Free Version



5.3±0.2

**DO-201AD** 

# Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

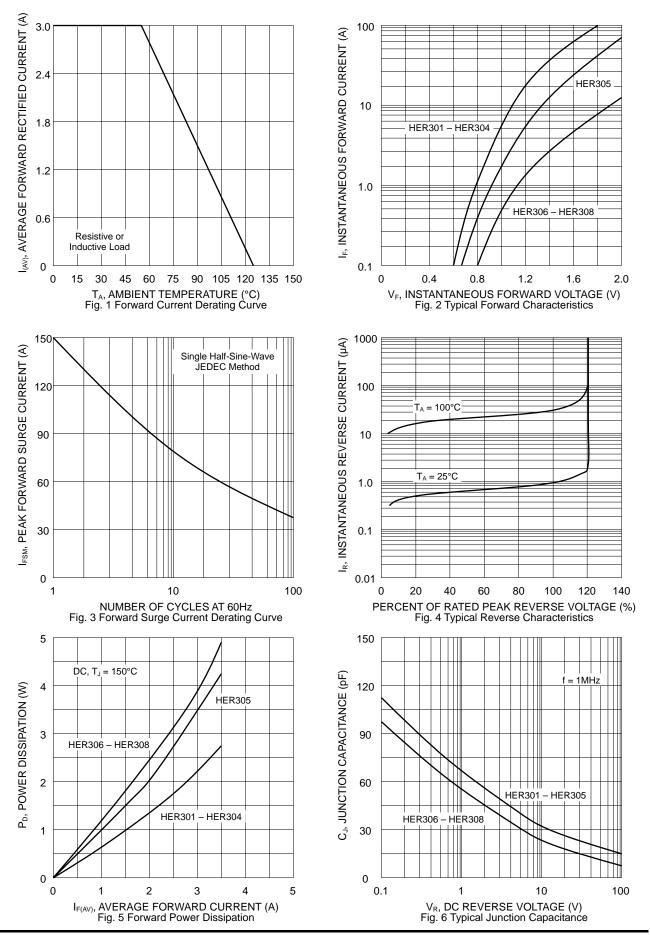
Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

| Characteristic  | Symbol             | HER<br>301  | HER<br>302 | HER<br>303 | HER<br>304 | HER<br>305 | HER<br>306 | HER<br>307 | HER<br>308 | Unit |
|---|--------------------|-------------|------------|------------|------------|------------|------------|------------|------------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                                | VRRM<br>VRWM<br>VR | 50          | 100        | 200        | 300        | 400        | 600        | 800        | 1000       | V    |
| RMS Reverse Voltage   | VR(RMS)            | 35          | 70         | 140        | 210        | 280        | 420        | 560        | 700        | V    |
| Average Rectified Output Current (Note 1) @T <sub>A</sub> = 55°C  | lo                 | 3.0         |            |            |            |            |            |            |            | Α    |
| Non-Repetitive Peak Forward Surge Current<br>8.3ms Single Half Sine-Wave Superimposed on<br>Rated Load (JEDEC Method) | Іғѕм               | 150         |            |            |            |            |            |            | А          |      |
| Forward Voltage @I <sub>F</sub> = 3.0A  | VFM                | 1.0 1.3     |            |            |            | 1.7        |            |            | V          |      |
|   | lгм                | 10<br>100   |            |            |            |            |            |            |            | μΑ   |
| Reverse Recovery Time (Note 2)  | t <sub>rr</sub>    | 50 75       |            |            |            |            |            | nS         |            |      |
| Typical Junction Capacitance (Note 3)   | CJ                 | 45          |            |            |            | 36         |            | pF         |            |      |
| Typical Thermal Resistance Junction to Ambient (Note 1) Typical Thermal Resistance Junction to Lead (Note 1)          | R JA<br>R JL       | 20<br>8.5   |            |            |            |            |            |            | °C/W       |      |
| Operating Temperature Range   | TJ                 | -65 to +125 |            |            |            |            |            |            | °C         |      |
| Storage Temperature Range   | Тѕтс               | -65 to +150 |            |            |            |            |            |            | °C         |      |

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case.

- 2. Measured with  $I_F = 0.5A$ ,  $I_R = 1.0A$ ,  $I_{RR} = 0.25A$ .
- 3. Measured at 1.0 MHz and Applied Reverse Voltage of 4.0V D.C.

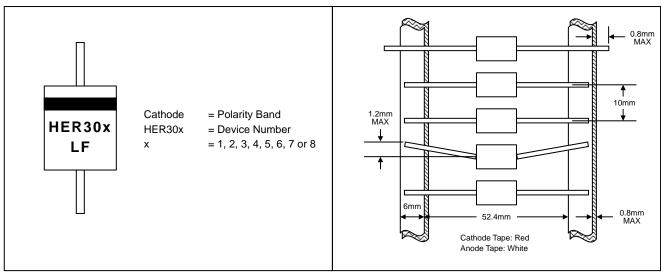






## **MARKING INFORMATION**

### **TAPING SPECIFICATIONS**



### PACKAGING INFORMATION

